

N-channel 40 V, 0.97 mOhm, Standard level MOSFET in LFPAK56

4 January 2024

Product data sheet

### 1. General description

Automotive qualified N-channel MOSFET using the latest Trench 15 low ohmic enhanced-Trench Bottom Oxide (e-TBO) technology, providing high ruggedness at low R<sub>DSon</sub>, housed in an LFPAK56 package. This product has been fully designed and qualified to meet AEC-Q101 requirements delivering high performance and endurance.

### 2. Features and benefits

- Fully automotive qualified to AEC-Q101:
  - 175 °C rating suitable for thermally demanding environments
- Trench 15 e-TBO technology:
  - Merging benefits of Superjunction technology (high ruggedness) and Split-Gate technology (low R<sub>DSon</sub>)
- · Fast and efficient switching with high damping and low spiking
- Tight  $V_{GS(th)}$  limits enable easy paralleling of MOSFETs
- LFPAK Gull Wing leads:
  - High Board Level Reliability absorbing mechanical stress during thermal cycling, unlike traditional QFN packages
  - · Visual (AOI) soldering inspection, no need for expensive x-ray equipment
  - · Easy solder wetting for good mechanical solder joints
- LFPAK copper clip technology:
  - Improved reliability, with reduced Rth, RDSon and package inductance
  - Increases maximum current capability and improved current spreading

### 3. Applications

- 12 V automotive systems
- Motor, lighting and solenoid control
- Reverse battery protection
- Ultra high-performance power switching

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C		-	-	40	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	[1]	-	-	320	A
Static charact	eristics						
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 25 °C; Fig. 12		0.57	0.81	0.97	mΩ

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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Dynamic chara	cteristics					
Q <sub>G(tot)</sub>	total gate charge	I <sub>D</sub> = 25 A; V <sub>DS</sub> = 32 V; V <sub>GS</sub> = 10 V; T <sub>j</sub> = 25 °C; <u>Fig. 14; Fig. 15</u>	81	135	189	nC

[1] This current had been successfully demonstrated during product characterisation. In practical applications the current will be limited by PCB, thermal design and operating temperature.

### 5. Pinning information

Table 2. Pinning information								
Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	S	source	mb					
2	S	source		D				
3	S	source	a					
4	G	gate		G_(₽, ₽)				
mb	D	mounting base; connected to drain	LFPAK56; Power- SO8 (SOT669)	mbb076 S				

### 6. Ordering information

Table 3. Ordering information			
	Name	Description	Version
BUK7Y1R0-40N	LFPAK56; Power-SO8	plastic, single-ended surface-mounted package; 4 terminals	SOT669

### 7. Marking

#### Table 4. Marking codes

Type number	Marking code
BUK7Y1R0-40N	71N040Y

### 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). T<sub>i</sub> = 25 °C unless otherwise stated.

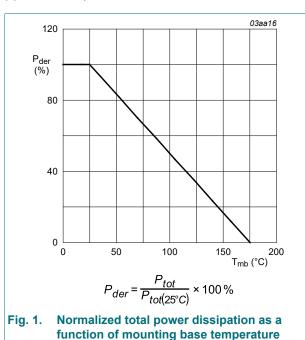
Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	25 °C ≤ T <sub>j</sub> ≤ 175 °C		-	40	V
V <sub>GS</sub>	gate-source voltage			-20	20	V
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>		-	268	W
ID	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	[1]	-	320	А
				-	262	А
I <sub>DM</sub>	peak drain current	pulsed; $t_p \le 10 \ \mu$ s; $T_{mb} = 25 \ ^{\circ}C$ ; <u>Fig. 3</u> ; Fig. 4	[1]	-	1465	A
T <sub>stg</sub>	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
Source-drain	n diode					_
I <sub>S</sub>	source current	T <sub>mb</sub> = 25 °C	[1]	-	268	А
I <sub>SM</sub>	peak source current	pulsed; t <sub>p</sub> ≤ 10 µs; T <sub>mb</sub> = 25 °C		-	1465	А
Avalanche r	uggedness	1				
E <sub>DS(AL)S</sub>	non-repetitive drain- source avalanche energy	$\begin{array}{l} I_{D} = 190 \; \text{A}; \; V_{sup} \leq \; 40 \; \text{V}; \; R_{GS} = 50 \; \Omega; \\ V_{GS} = 10 \; \text{V}; \; T_{j(init)} = 25 \; ^{\circ}\text{C}; \; unclamped; \\ \hline Fig. \; 5 \end{array}$	[2] [3]	-	145	mJ
I <sub>AS</sub>	non-repetitive avalanche current		[4]	-	190	A

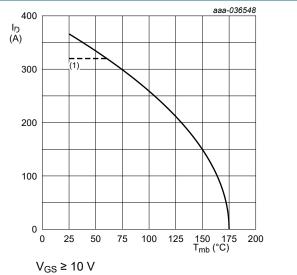
[1] This current had been successfully demonstrated during product characterisation. In practical applications the current will be limited by PCB, thermal design and operating temperature.

[2] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.

[3] Refer to application note AN10273 for further information.

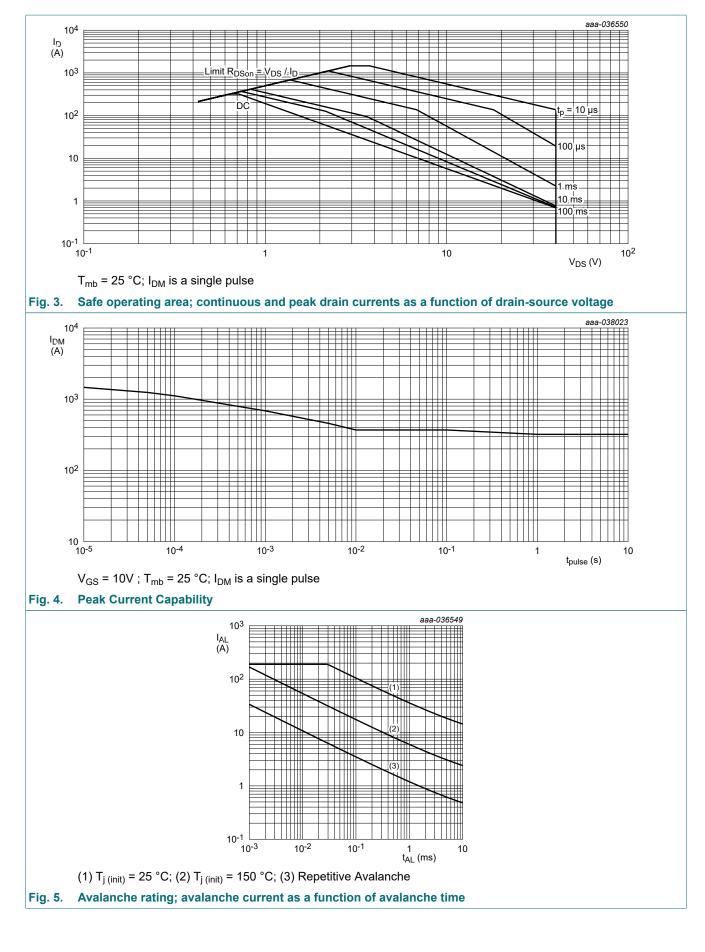
[4] Protected by 100% test.





(1) 320 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

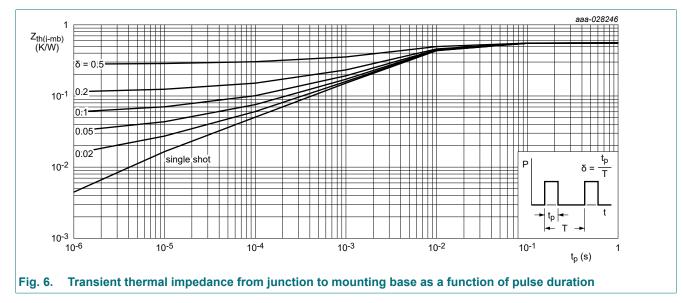
## Fig. 2. Continuous drain current as a function of mounting base temperature



### 9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	Fig. <u>6</u>		-	0.48	0.56	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient		[1]	-	24	-	K/W

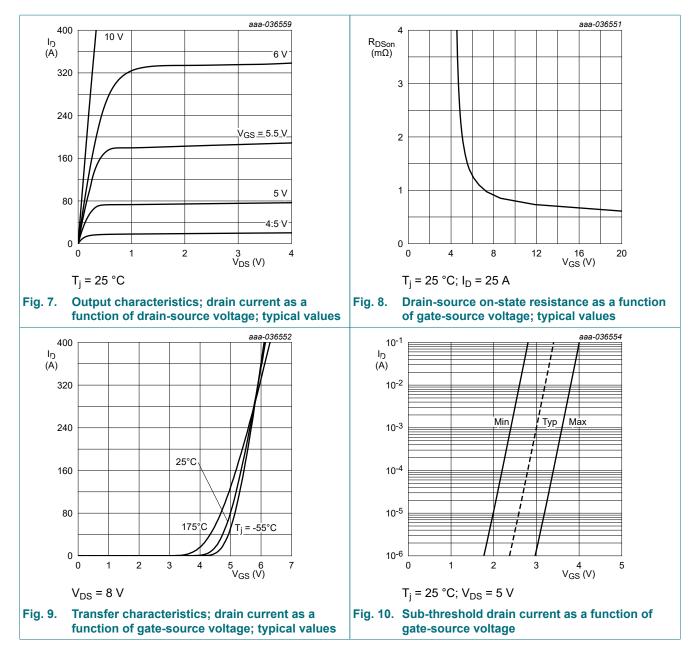
[1] Device on 4 layer PCB. Refer to TN00008 for further information.



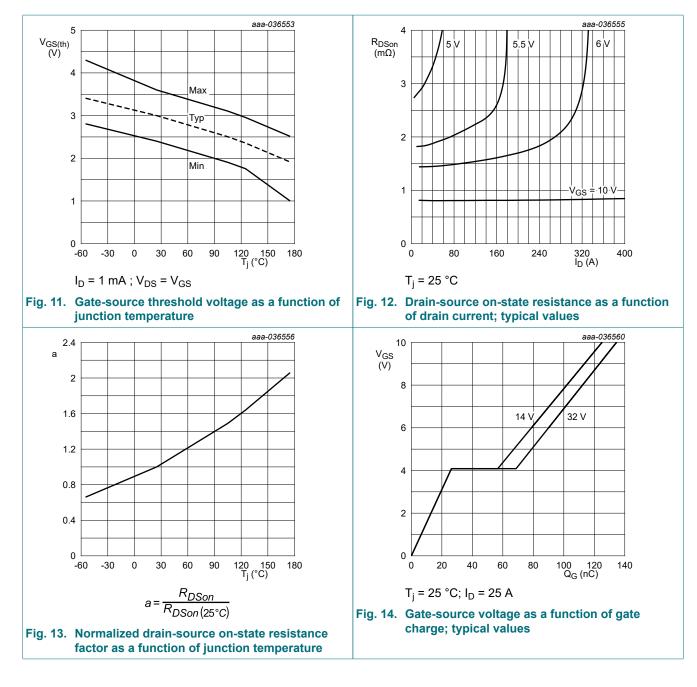
### **10. Characteristics**

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
Static chara	acteristics						
V <sub>(BR)DSS</sub>	drain-source	I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C		40	43	-	V
. ,	breakdown voltage	I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = -40 °C		-	40.5	-	V
		I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = -55 °C		36	40	-	V
V <sub>GS(th)</sub>	gate-source threshold	I <sub>D</sub> = 1 mA; V <sub>DS</sub> =V <sub>GS</sub> ; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>		2.4	3	3.6	V
( )	voltage	I <sub>D</sub> = 1 mA; V <sub>DS</sub> =V <sub>GS</sub> ; T <sub>j</sub> = -55 °C; <u>Fig. 11</u>		-	-	4.3	V
		I <sub>D</sub> = 1 mA; V <sub>DS</sub> =V <sub>GS</sub> ; T <sub>j</sub> = 175 °C; Fig. 11		1	-	-	V
I <sub>DSS</sub>	drain leakage current	V <sub>DS</sub> = 40 V; V <sub>GS</sub> = 0 V; T <sub>i</sub> = 25 °C		-	0.1	1	μA
		V <sub>DS</sub> = 16 V; V <sub>GS</sub> = 0 V; T <sub>i</sub> = 125 °C		-	1.1	10	μA
		V <sub>DS</sub> = 40 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 175 °C		-	80	500	μA
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C		-	2	100	nA
		V <sub>GS</sub> = -20 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C		-	2	100	nA
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 25 °C; Fig. 12		0.57	0.81	0.97	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 105 °C; Fig. 13		0.77	1.15	1.46	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 125 °C; Fig. 13		0.84	1.25	1.6	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 25 A; T <sub>j</sub> = 175 °C; Fig. 13		1	1.52	2	mΩ
R <sub>G</sub>	gate resistance	f = 1 MHz; T <sub>j</sub> = 25 °C		0.2	0.63	1.6	Ω
Dynamic cł	naracteristics	· · ·				-	
Q <sub>G(tot)</sub>	total gate charge $I_D = 25 \text{ A}; V_{DS} = 32 \text{ V}; V_{GS} = 10 \text{ V};$			81	135	189	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C; <u>Fig. 14;</u> <u>Fig. 15</u>		14	26	38	nC
Q <sub>GD</sub>	gate-drain charge	-		12	42	72	nC
C <sub>iss</sub>	input capacitance	V <sub>DS</sub> = 25 V; V <sub>GS</sub> = 0 V; f = 1 MHz;		4552	7587	10622	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C; <u>Fig. 16</u>		1166	1666	2166	pF
C <sub>rss</sub>	reverse transfer capacitance			252	631	1010	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = 30 V; R <sub>L</sub> = 1.2 Ω; V <sub>GS</sub> = 10 V;		-	25	-	ns
t <sub>r</sub>	rise time	R <sub>G(ext)</sub> = 5 Ω; T <sub>j</sub> = 25 °C		-	49	-	ns
t <sub>d(off)</sub>	turn-off delay time			-	79	-	ns
t <sub>f</sub>	fall time	1		-	58	-	ns
Source-dra	in diode					-	
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = 25 A; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 25 °C; <u>Fig. 17</u>		-	0.79	1	V
t <sub>rr</sub>	reverse recovery time	$I_{S} = 25 \text{ A}; \text{ d}I_{S}/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$		-	34	-	ns
Q <sub>r</sub>	recovered charge	V <sub>DS</sub> = 20 V; T <sub>j</sub> = 25 °C; <u>Fig. 18</u>	[1]	-	24	-	nC

[1] includes capacitive recovery

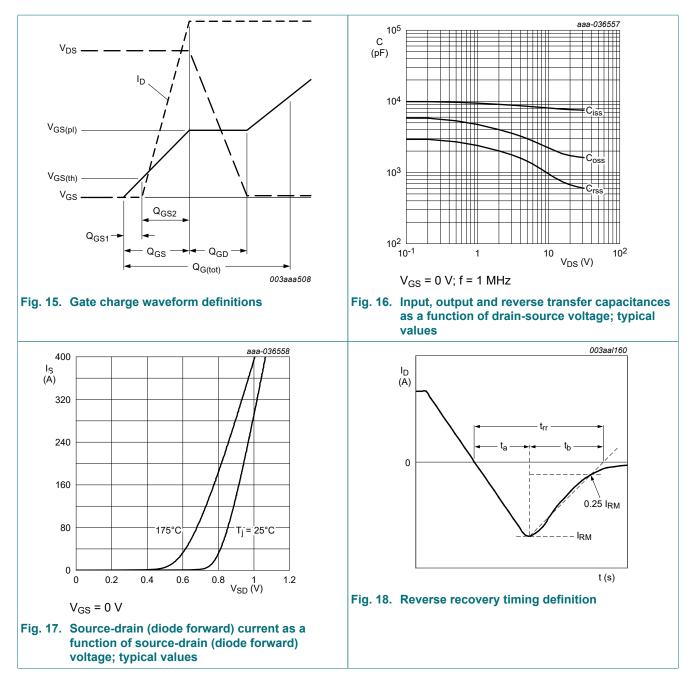


**Product data sheet** 



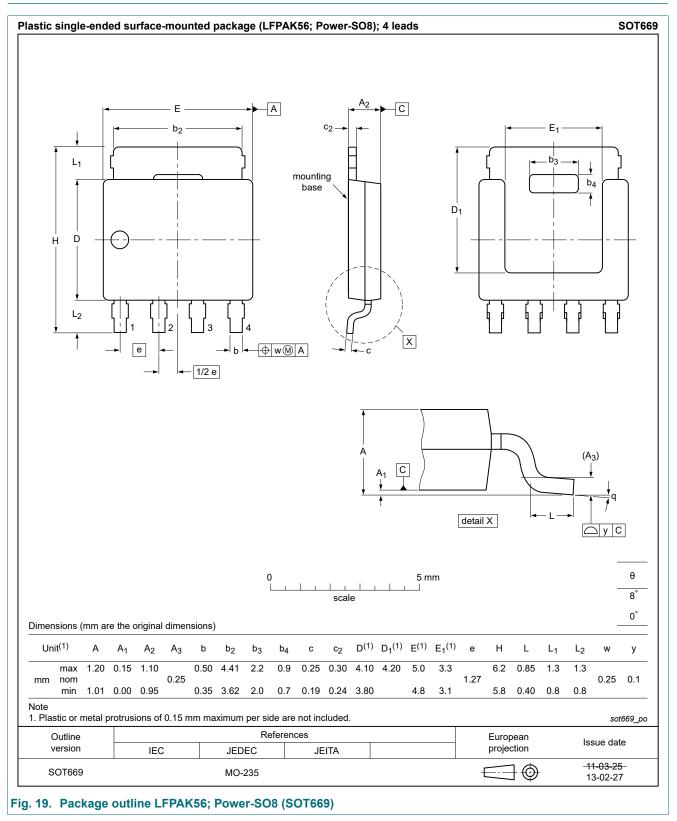
**Product data sheet** 

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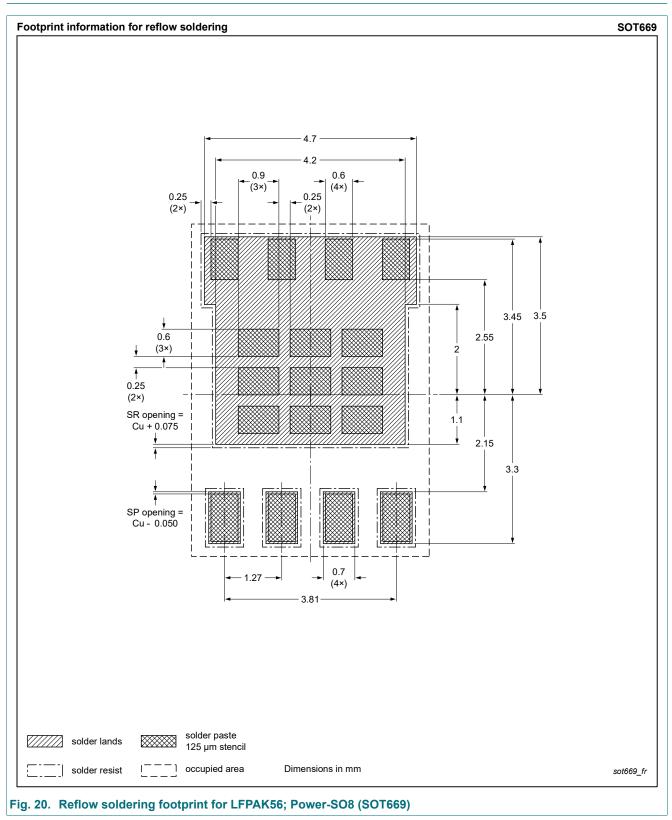


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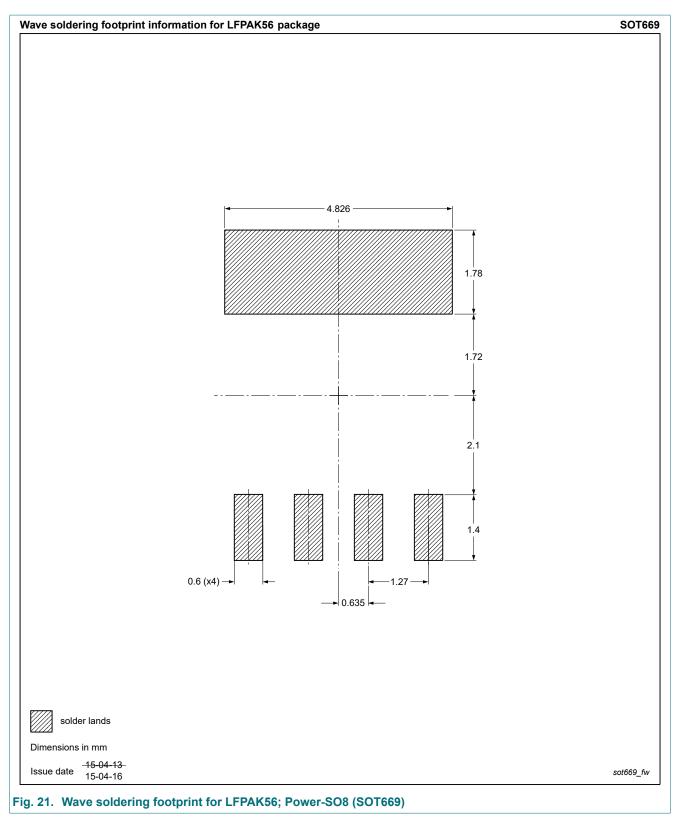
### **11. Package outline**



### 12. Soldering



#### N-channel 40 V, 0.97 mOhm, Standard level MOSFET in LFPAK56



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### 13. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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